FAIRCHILD SEMICONDUCTOR™

March 1988
Revised October 2000

74F646 • 74F646B • 74F648
Octal Transceiver/Register with 3-STATE Outputs

General Description

These devices consist of bus transceiver circuits with 3-STATE, D-type flip-flops, and control circuitry arranged for multiplexed transmission of data directly from the input bus or from the internal registers. Data on the A or B bus will be clocked into the registers as the appropriate clock pin goes to a high logic level. Control $\overline{G}$ and direction pins are provided to control the transceiver function. In the transceiver mode, data present at the high impedance port may be stored in either the A or the B register or in both. The select controls can multiplex stored and real-time (transparent mode) data. The direction control determines which bus will receive data when the enable control $\overline{G}$ is Active LOW. In the isolation mode (control $\overline{G}$ HIGH), A data may be stored in the B register and/or B data may be stored in the A register.

Features

- Independent registers for A and B buses
- Multiplexed real-time and stored data
- 74F648 has inverting data paths
- 74F646/74F646B have non-inverting data paths
- 74F646B is a faster version of the 74F646
- 3-STATE outputs
- 300 mil slim DIP

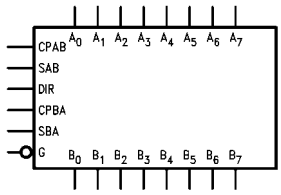
Ordering Code:

Order Number	Package Number	Package Description
74F646SC	M24B	24-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300 Wide
74F646MSA	MSA24	24-Lead Shrink Small Outline Package (SSOP), EIAJ TYPE II, 5.3mm Wide
74F646SPC	N24C	24-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide
74F646BSC	M24B	24-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300 Wide
74F646BSPC	N24C	24-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide
74F648SC	M24B	24-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300 Wide
74F648SPC	N24C	24-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide

Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

Logic Symbols

74F646/74F646B



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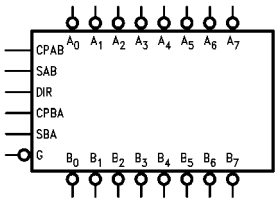
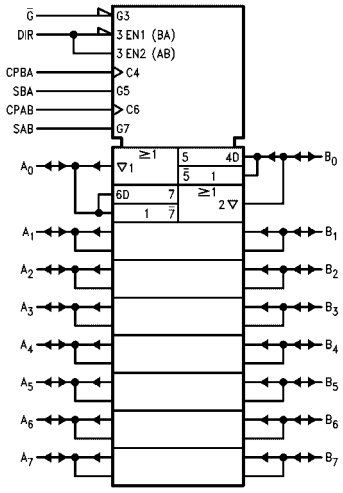
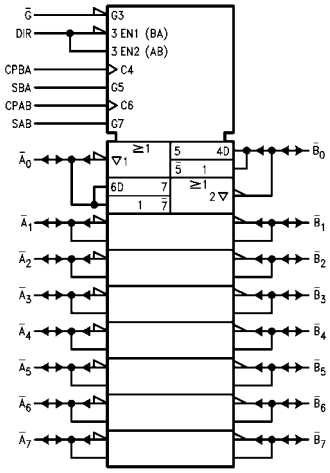


IEEE/IEC
74F646/74F646B

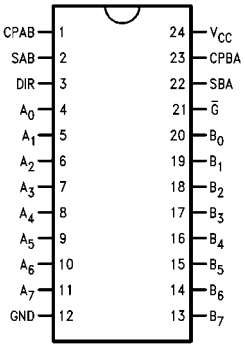


IEEE/IEC
74F648



Connection Diagrams

74F646/74F646B



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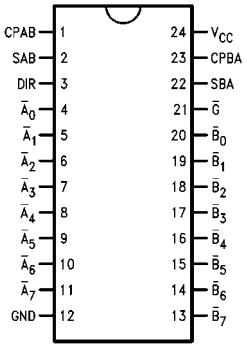


Unit Loading/Fan Out

Pin Names	Description	U.L. HIGH/LOW	Input I_{IH}/I_{IL} Output I_{OH}/I_{OL}
A_0–A_7	Data Register A Inputs/	3.5/1.083	70 μA/–650 μA
	3-STATE Outputs	600/106.6 (80)	–12 mA/64 mA (48 mA)
B_0–B_7	Data Register B Inputs/	3.5/1.083	70 μA/–650 μA
	3-STATE Outputs	600/106.6 (80)	–12 mA/64 mA (48 mA)
CPAB, CPBA	Clock Pulse Inputs	1.0/1.0	20 μA/–0.6 mA
SAB, SBA	Select Inputs	1.0/1.0	20 μA/–0.6 mA
$\overline{G}$	Output Enable Input	1.0/1.0	20 μA/–0.6 mA
DIR	Direction Control Input	1.0/1.0	20 μA/–0.6 mA

Function Table

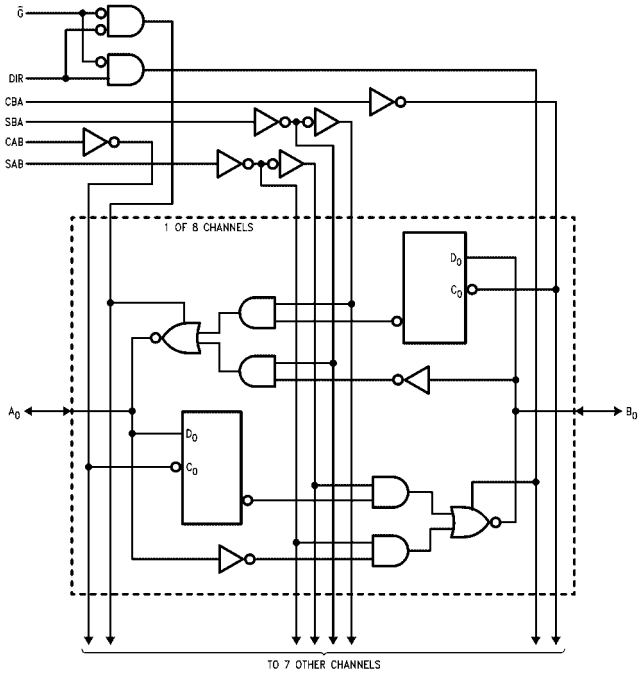
Inputs						Data I/O (Note 1)		Function
$\overline{G}$	DIR	CPAB	CPBA	SAB	SBA	A_0–A_7	B_0–B_7	
H	X	H or L	H or L	X	X			Isolation
H	X	⌐	X	X	X	Input	Input	Clock A_n Data into A Register
H	X	X	⌐	X	X			Clock B_n Data into B Register
L	H	X	X	L	X			A_n to B_n—Real Time (Transparent Mode)
L	H	⌐	X	L	X	Input	Output	Clock A_n Data into A Register
L	H	H or L	X	H	X			A Register to B_n (Stored Mode)
L	H	⌐	X	H	X			Clock A_n Data into A Register and Output to B_n
L	L	X	X	X	L			B_n to A_n—Real Time (Transparent Mode)
L	L	X	⌐	X	L	Output	Input	Clock B_n Data into B Register
L	L	X	H or L	X	H			B Register to A_n (Stored Mode)
L	L	X	⌐	X	H			Clock B_n Data into B Register and Output to A_n

H = HIGH Voltage Level
L = LOW Voltage Level
X = Irrelevant
⌐ = LOW-to-HIGH Transition

Note 1: The data output functions may be enabled or disabled by various signals at the $\overline{G}$ and DIR Inputs. Data input functions are always enabled; i.e., data at the bus pins will be stored on every LOW-to-HIGH transition of the clock inputs.

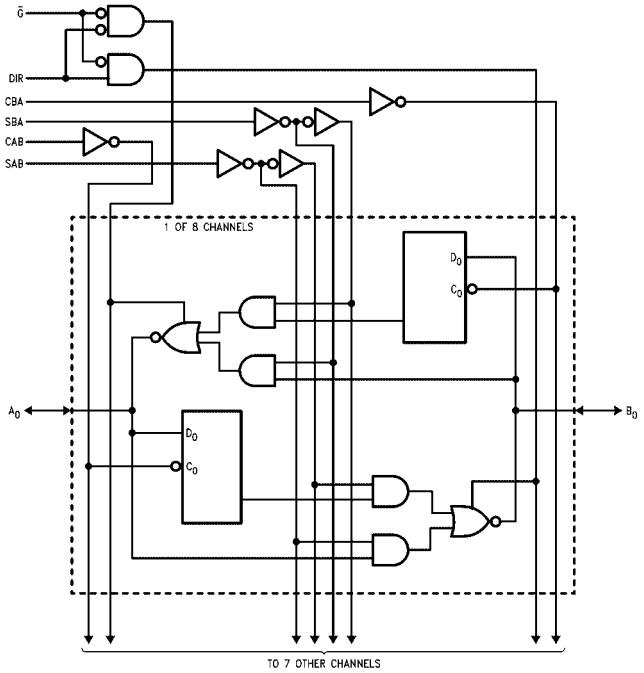
Logic Diagrams

74F646/74F646B



Please note that this diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays.

74F648



Please note that this diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays.

Absolute Maximum Ratings(Note 2)

Storage Temperature	−65°C to +150°C
Ambient Temperature under Bias	−55°C to +125°C
Junction Temperature under Bias	−55°C to +150°C
V_{CC} Pin Potential to Ground Pin	−0.5V to +7.0V
Input Voltage (Note 3)	−0.5V to +7.0V
Input Current (Note 3)	−30 mA to +5.0 mA
Voltage Applied to Output	
in HIGH State (with V_{CC} = 0V)	
Standard Output	−0.5V to V_{CC}
3-STATE Output	−0.5V to +5.5V
Current Applied to Output	
in LOW State (Max)	twice the rated I_{OL} (mA)
ESD Last Passing Voltage (Min)	4000V

Recommended Operating Conditions

Free Air Ambient Temperature	0°C to +70°C
Supply Voltage	+4.5V to +5.5V

Note 2: Absolute maximum ratings are values beyond which the device may be damaged or have its useful life impaired. Functional operation under these conditions is not implied.

Note 3: Either voltage limit or current limit is sufficient to protect inputs.

DC Electrical Characteristics

Symbol	Parameter	Min	Typ	Max	Units	V_{CC}	Conditions
V_{IH}	Input HIGH Voltage	2.0			V		Recognized as a HIGH Signal
V_{IL}	Input LOW Voltage			0.8	V		Recognized as a LOW Signal
V_{CD}	Input Clamp Diode Voltage			−1.2	V	Min	I_{IN} = −18 mA (Non I/O Pins)
V_{OH}	Output HIGH Voltage 10% V_{CC}	2.0			V	Min	I_{OH} = −15 mA (A_n, B_n)
V_{OL}	Output LOW Voltage 10% V_{CC}			0.55	V	Min	I_{OL} = 64 mA (A_n, B_n)
I_{IH}	Input HIGH Current			5.0	µA	Max	V_{IN} = 2.7V (Non I/O Pins)
I_{BVI}	Input HIGH Current Breakdown Test			7.0	µA	Max	V_{IN} = 7.0V (Non I/O Pins)
I_{BVIT}	Input HIGH Current Breakdown (I/O)			0.5	mA	Max	V_{IN} = 5.5V (A_n, B_n)
I_{CEX}	Output HIGH Leakage Current			50	µA	Max	V_{OUT} = V_{CC}
V_{ID}	Input Leakage Test	4.75			V	0.0	I_{ID} = 1.9 µA All Other Pins Grounded
I_{OD}	Output Leakage Circuit Current			3.75	µA	0.0	V_{IOD} = 150 mV All Other Pins Grounded
I_{IL}	Input LOW Current			−0.6	mA	Max	V_{IN} = 0.5V (Non I/O Pins)
I_{IH} + I_{OZH}	Output Leakage Current			70	µA	Max	V_{OUT} = 2.7V (A_n, B_n)
I_{IL} + I_{OZL}	Output Leakage Current			−650	µA	Max	V_{OUT} = 0.5V (A_n, B_n)
I_{OS}	Output Short-Circuit Current	−100		−225	mA	Max	V_{OUT} = 0V
I_{ZZ}	Bus Drainage Test			500	µA	0.0V	V_{OUT} = 5.25V
I_{CCH}	Power Supply Current			135	mA	Max	V_O = HIGH
I_{CCL}	Power Supply Current			150	mA	Max	V_O = LOW
I_{CCZ}	Power Supply Current			150	mA	Max	V_O = HIGH Z

AC Electrical Characteristics 74F646/74F648

Symbol	Parameter	$T_A = +25°C$, $V_{CC} = +5.0V$, $C_L = 50$ pF		$T_A = -55°C$ to $+125°C$, $V_{CC} = +5.0V$, $C_L = 50$ pF		$T_A = 0°C$ to $+70°C$, $V_{CC} = +5.0V$, $C_L = 50$ pF		Units
		Min	Max	Min	Max	Min	Max	
f_{MAX}	Maximum Clock Frequency	90		75		90		MHz
t_{PLH}	Propagation Delay	2.0	7.0	2.0	8.5	2.0	8.0	ns
t_{PHL}	Clock to Bus	2.0	8.0	2.0	9.5	2.0	9.0	
t_{PLH}	Propagation Delay	1.0	7.0	1.0	8.0	1.0	7.5	ns
t_{PHL}	Bus to Bus (74F646)	1.0	6.5	1.0	8.0	1.0	7.0	
t_{PLH}	Propagation Delay	2.0	8.5	1.0	10.0	2.0	9.0	ns
t_{PHL}	Bus to Bus (74F648)	1.0	7.5	1.0	9.0	1.0	8.0	
t_{PLH}	Propagation Delay	2.0	8.5	2.0	11.0	2.0	9.5	ns
t_{PHL}	SBA or SAB to A or B	2.0	8.0	2.0	10.0	2.0	9.0	
t_{PZH}	Enable Time	2.0	8.5	2.0	10.0	2.0	9.0	ns
t_{PZL}	$\overline{OE}$ to A or B	2.0	12.0	2.0	13.5	2.0	12.5	
t_{PHZ}	Disable Time	1.0	7.5	1.0	9.0	1.0	8.5	ns
t_{PLZ}	$\overline{OE}$ to A or B	2.0	9.0	2.0	11.0	2.0	9.5	
t_{PZH}	Enable Time	2.0	14.0	2.0	16.0	2.0	15.0	ns
t_{PZL}	DIR to A or B	2.0	13.0	2.0	15.0	2.0	14.0	
t_{PHZ}	Disable Time	1.0	9.0	1.0	10.0	1.0	9.5	ns
t_{PLZ}	DIR to A or B	2.0	11.0	2.0	12.0	2.0	11.5	

AC Operating Requirements 74F646/74F648

Symbol	Parameter	$T_A = +25°C$, $V_{CC} = +5.0V$		$T_A = -55°C$ to $+125°C$, $V_{CC} = +5.0V$		$T_A = 0°C$ to $+70°C$, $V_{CC} = +5.0V$		Units
		Min	Max	Min	Max	Min	Max	
$t_S(H)$	Setup Time, HIGH or LOW	5.0		5.0		5.0		ns
$t_S(L)$	Bus to Clock	5.0		5.0		5.0		
$t_H(H)$	Hold Time, HIGH or LOW	2.0		2.5		2.0		ns
$t_H(L)$	Bus to Clock	2.0		2.5		2.0		
$t_W(H)$	Clock Pulse Width	5.0		5.0		5.0		ns
$t_W(L)$	HIGH or LOW	5.0		5.0		5.0		

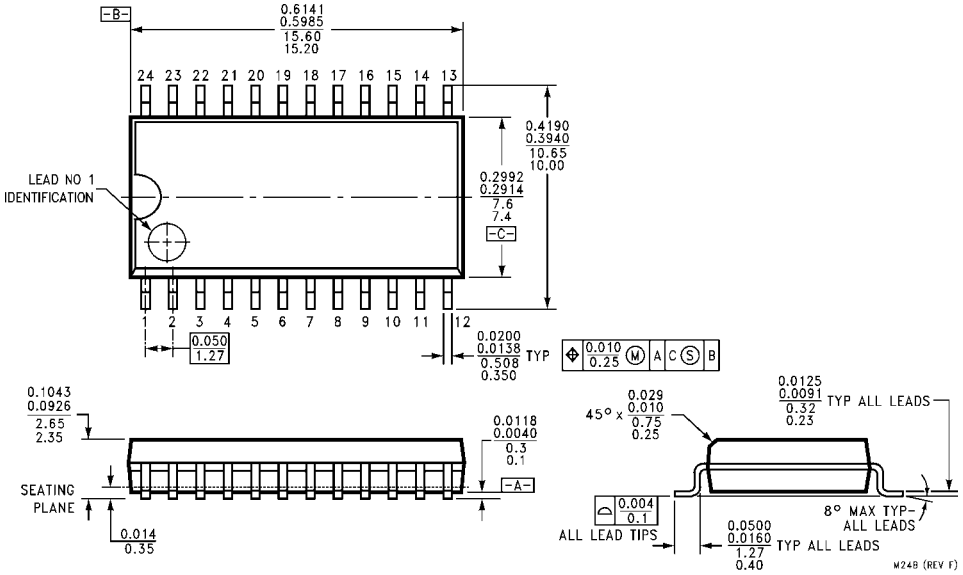
AC Electrical Characteristics 74F646B

Symbol	Parameter	$T_A = +25°C$ $V_{CC} = +5.0V$ $C_L = 50$ pF		$T_A = -55°C$ to $+125°C$ $V_{CC} = +5.0V$ $C_L = 50$ pF		$T_A = 0°C$ to $+70°C$ $V_{CC} = +5.0V$ $C_L = 50$ pF		Units
		Min	Max	Min	Max	Min	Max	
f_{MAX}	Maximum Clock Frequency	165				150		MHz
t_{PLH}	Propagation Delay	2.5	7.0			2.5	8.0	ns
t_{PHL}	Clock to Bus	3.0	7.5			3.0	8.0	
t_{PLH}	Propagation Delay	2.0	6.0			2.0	7.0	ns
t_{PHL}	Bus to Bus	2.0	6.0			2.0	7.0	
t_{PLH}	Propagation Delay	2.5	7.5			2.5	8.5	ns
t_{PHL}	SBA or SAB to A or B	2.5	7.5			2.5	8.5	
t_{PZH}	Enable Time	2.5	6.5			2.5	8.0	ns
t_{PZL}	$\overline{OE}$ to A or B	2.5	9.0			2.5	10.0	
t_{PHZ}	Disable Time	1.5	6.5			1.5	7.5	ns
t_{PLZ}	$\overline{OE}$ to A or B	2.0	7.0			2.0	8.5	
t_{PZH}	Enable Time	2.0	7.0			2.0	8.5	ns
t_{PZL}	DIR to A or B	3.0	9.5			3.0	10.0	
t_{PHZ}	Disable Time	1.5	7.5			1.5	8.5	ns
t_{PLZ}	DIR to A or B	2.5	8.5			2.5	9.5	

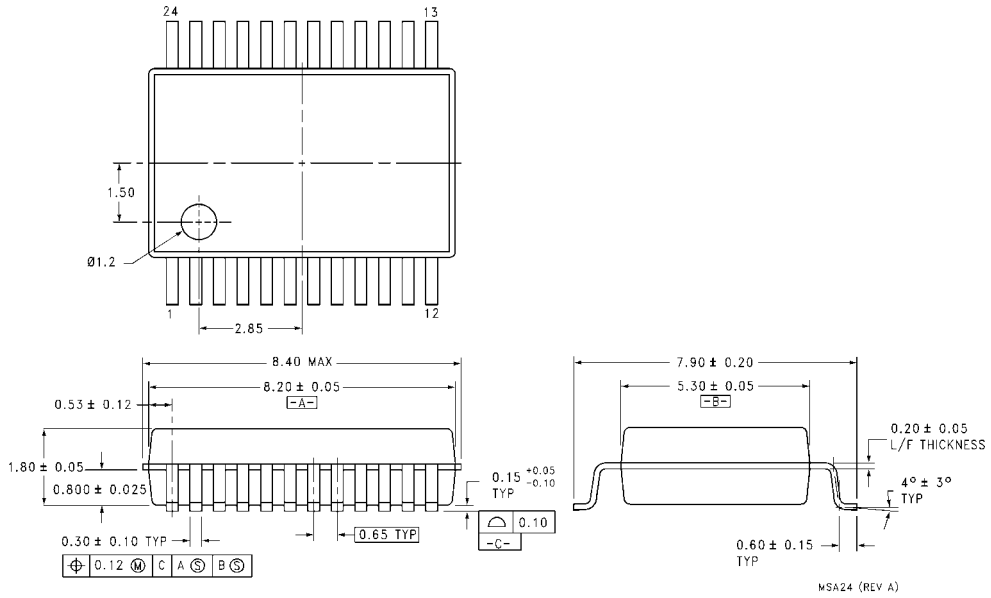
AC Operating Requirements 74F646B

Symbol	Parameter	$T_A = +25°C$ $V_{CC} = +5.0V$		$T_A = -55°C$ to $+125°C$ $V_{CC} = +5.0V$		$T_A = 0°C$ to $+70°C$ $V_{CC} = +5.0V$		Units
		Min	Max	Min	Max	Min	Max	
$t_S(H)$	Setup Time, HIGH or LOW	5.0				4.0		ns
$t_S(L)$	Bus to Clock	5.0				4.0		
$t_H(H)$	Hold Time, HIGH or LOW	1.5				1.5		ns
$t_H(L)$	Bus to Clock	1.5				1.5		
$t_W(H)$	Clock Pulse Width	5.0				5.0		ns
$t_W(L)$	HIGH or LOW	5.0				5.0		

Physical Dimensions inches (millimeters) unless otherwise noted

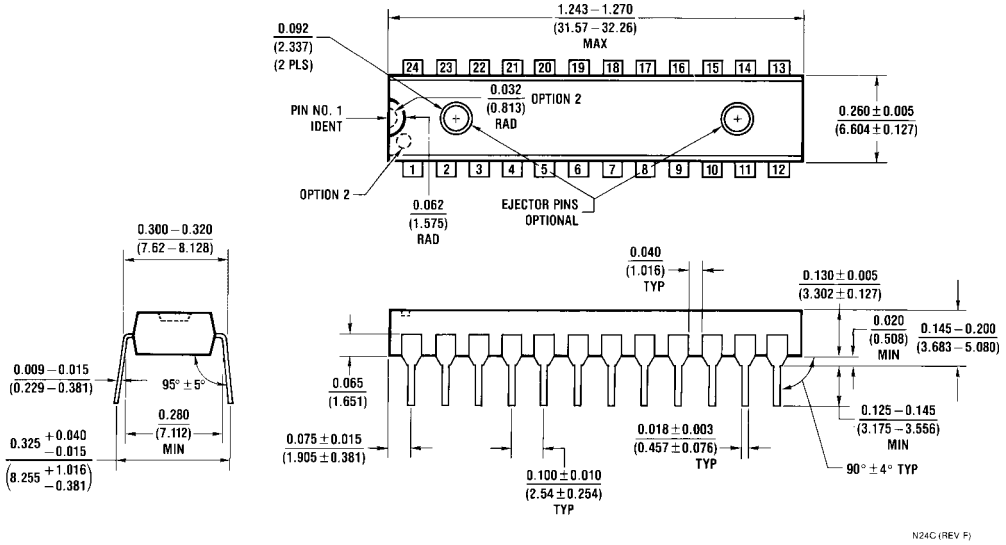


24-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300 Wide
Package Number M24B



24-Lead Shrink Small Outline Package (SSOP), EIAJ TYPE II, 5.3mm Wide
Package Number MSA24

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



24-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide
Package Number N24C